NSN 5961-01-331-3950

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-331-3950 **Inclosure Material:** Plastic **Overall Length:** Between 0.175 inches and 0.185 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.670 inches **Overall Width:** 0.145 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -20.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source and -1.0 gate to source cutoff voltage and -3.0 gate to source cutoff voltage **Current Rating Per Characteristic:** -3.00 nanoamperes reverse gate current with all other terminals short-circuit to source, junction-gate and 30.00 milliamperes zero-gate-voltage drain current **Power Rating Per Characteristic:** 200.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No